74HC123-Q100; 74HCT123-Q100

Dual retriggerable monostable multivibrator with reset

Rev. 1 — 1 August 2012

Product data sheet

1. General description

The 74HC123-Q100; 74HCT123-Q100 are high-speed Si-gate CMOS devices and are pin compatible with Low-power Schottky TTL (LSTTL). They are specified in compliance with JEDEC standard no. 7A.

The 74HC123-Q100; 74HCT123-Q100 are dual retriggerable monostable multivibrators with output pulse width control by three methods:

- 1. The basic pulse is defined by the selection of the external resistor (R_{EXT}) and capacitor (C_{EXT}).
- 2. Once triggered, the basic output pulse width may be extended by retriggering the gated active LOW-going edge input (nA) or the active HIGH-going edge input (nB). By repeating this process, the output pulse period (nQ = HIGH, nQ = LOW) can be made as long as desired. Alternatively an output delay can be terminated at any time by a LOW-going edge on input nRD, which also inhibits the triggering.
- 3. An internal connection from nRD to the input gates makes it possible to trigger the circuit by a HIGH-going signal at input nRD as shown in Table 3.

Schmitt trigger action in the $n\overline{A}$ and nB inputs, makes the circuit highly tolerant to slower input rise and fall times.

This product has been qualified to the Automotive Electronics Council (AEC) standard Q100 (Grade 1) and is suitable for use in automotive applications.

2. Features and benefits

- Automotive product qualification in accordance with AEC-Q100 (Grade 1)
 - ◆ Specified from -40 °C to +85 °C and from -40 °C to +125 °C
- DC triggered from active HIGH or active LOW inputs
- Retriggerable for very long pulses up to 100 % duty factor
- Direct reset terminates output pulse
- Schmitt trigger action on all inputs except for the reset input
- ESD protection:
 - MIL-STD-883, method 3015 exceeds 2000 V
 - ♦ HBM JESD22-A114F exceeds 2000 V
 - ♦ MM JESD22-A115-A exceeds 200 V (C = 200 pf, R = 0 Ω)
- Specified from -40 °C to +85 °C and from -40 °C to +125 °C

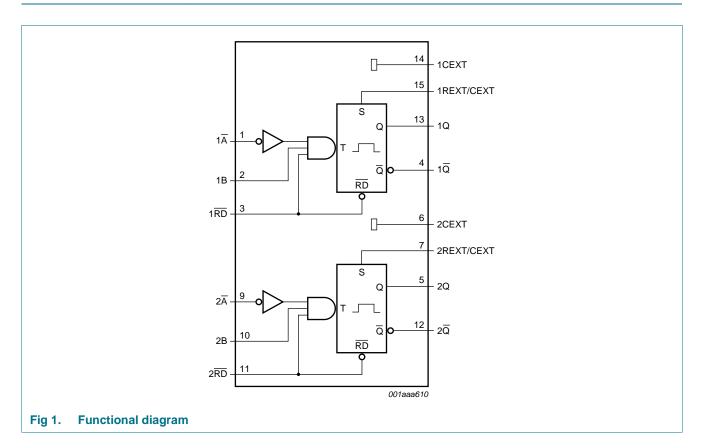


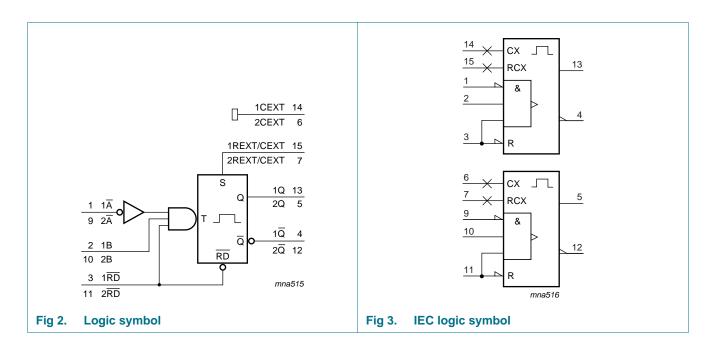
3. Ordering information

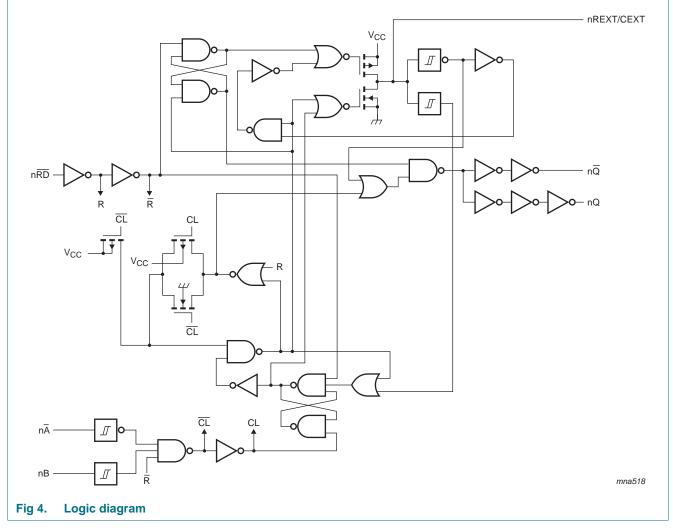
Table 1. Ordering information

Type number	Package			
	Temperature range	Name	Description	Version
74HC123D-Q100	–40 °C to +125 °C	SO16	plastic small outline package; 16 leads;	SOT109-1
74HCT123D-Q100			body width 3.9 mm	
74HC123PW-Q100	–40 °C to +125 °C	TSSOP16	plastic thin shrink small outline package; 16 leads;	SOT403-1
74HCT123PW-Q100			body width 4.4 mm	
74HC123BQ-Q100	–40 °C to +125 °C	DHVQFN16	plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 16 terminals; body $2.5\times3.5\times0.85$ mm	SOT763-1

4. Functional diagram

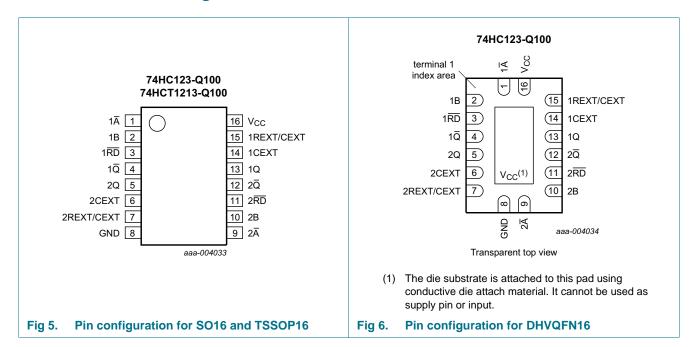






5. Pinning information

5.1 Pinning



5.2 Pin description

Table 2. Pin description

Symbol	Pin	Description	
1 A	1	negative-edge triggered input 1	
1B	2	positive-edge triggered input 1	
1RD	3	direct reset LOW and positive-edge triggered input 1	
1Q	4	active LOW output 1	
2Q	5	active HIGH output 2	
2CEXT	6	external capacitor connection 2	
2REXT/CEXT	7	external resistor and capacitor connection 2	
GND	8	ground (0 V)	
2Ā	9	negative-edge triggered input 2	
2B	10	positive-edge triggered input 2	
2RD	11	direct reset LOW and positive-edge triggered input 2	
2Q	12	active LOW output 2	
1Q	13	active HIGH output 1	
1CEXT	14	external capacitor connection 1	
1REXT/CEXT	15	external resistor and capacitor connection 1	
V _{CC}	16	supply voltage	

6. Functional description

Table 3. Function table[1]

Input			Output	
nRD	nΑ	nB	nQ	nQ
L	X	X	L	Н
X	Н	X	<u>[2]</u>	H[2]
X	Χ	L	<u>[2]</u>	H[2]
Н	L	\uparrow	Л	T
Н	+	Н	Л	T
\uparrow	L	Н	Л	IJ

^[1] H = HIGH voltage level; L = LOW voltage level; X = don't care; ↑ = LOW-to-HIGH transition; ↓ = HIGH-to-LOW transition;

7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

					-
Symbol	Parameter	Conditions	Min	Max	Unit
V_{CC}	supply voltage		-0.5	+7	V
I _{IK}	input clamping current	$V_I < -0.5 \text{ V or } V_I > V_{CC} + 0.5 \text{ V}$	-	±20	mA
I _{OK}	output clamping current	$V_O < -0.5 \text{ V or } V_O > V_{CC} + 0.5 \text{ V}$	-	±20	mA
Io	output current	except for pins nREXT/CEXT; $V_O = -0.5 \text{ V}$ to $(V_{CC} + 0.5 \text{ V})$	-	±25	mA
I _{CC}	supply current		-	50	mA
I _{GND}	ground current		-	-50	mA
T _{stg}	storage temperature		-65	+150	°C
P _{tot}	total power dissipation				
	SO16 package		<u>[3]</u> _	500	mW
	TSSOP16 package		<u>[4]</u> _	500	mW
	DHVQFN16 package		<u>[5]</u> _	500	mW

^[3] For SO16 packages: P_{tot} derates linearly with 8 mW/K above 70 °C.

⁼ one HIGH level output pulse; = one LOW level output pulse.

^[2] If the monostable was triggered before this condition was established, the pulse continues as programmed.

^[4] For TSSOP16 packages: Ptot derates linearly with 5.5 mW/K above 60 °C.

^[5] For DHVQFN16 packages: P_{tot} derates linearly with 4.5 mW/K above 60 °C.

8. Recommended operating conditions

Table 5. Recommended operating conditions

Symbol	Parameter	Conditions	74H	IC123-Q	100	74H	CT123-0	Q100	Unit
			Min	Тур	Max	Min	Тур	Max	
V_{CC}	supply voltage		2.0	5.0	6.0	4.5	5.0	5.5	V
VI	input voltage		0	-	V_{CC}	0	-	V_{CC}	V
Vo	output voltage		0	-	V_{CC}	0	-	V_{CC}	V
Δt/ΔV	input transition rise and	nRD input							
	fall rate	$V_{CC} = 2.0 \text{ V}$	-	-	625	-	-	-	ns/V
		$V_{CC} = 4.5 \text{ V}$	-	1.67	139	-	1.67	139	ns/V
		$V_{CC} = 6.0 \text{ V}$	-	-	83	-	-	-	ns/V
T _{amb}	ambient temperature		-40	+25	+125	-40	+25	+125	°C

9. Static characteristics

Table 6. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		25 °C		-40 °C t	o +85 °C	–40 °C to	+125 °C	Unit
			Min	Тур	Max	Min	Max	Min	Max	
74HC123	3-Q100			•	'					'
V_{IH}	HIGH-level	V _{CC} = 2.0 V	1.5	1.2	-	1.5	-	1.5	-	V
	input voltage	V _{CC} = 4.5 V	3.15	2.4	-	3.15	-	3.15	-	V
		V _{CC} = 6.0 V	4.2	3.2	-	4.2	-	4.2	-	V
V _{IL}	LOW-level	V _{CC} = 2.0 V	-	8.0	0.5	-	0.5	-	0.5	V
	input voltage	V _{CC} = 4.5 V	-	2.1	1.35	-	1.35	-	1.35	V
		V _{CC} = 6.0 V	-	2.8	1.8	-	1.8	-	1.8	V
V_{OH}	HIGH-level	$V_I = V_{IH}$ or V_{IL}								
	output voltage	$I_{O} = -20 \mu A; V_{CC} = 2.0 V$	1.9	2.0	-	1.9	-	1.9	-	V
		$I_{O} = -20 \mu A; V_{CC} = 4.5 V$	4.4	4.5	-	4.4	-	4.4	-	V
		$I_{O} = -20 \mu A; V_{CC} = 6.0 V$	5.9	6.0	-	5.9	-	5.9	-	V
		$I_{O} = -4 \text{ mA}; V_{CC} = 4.5 \text{ V}$	3.98	4.32	-	3.84	-	3.7	-	V
		$I_{O} = -5.2 \text{ mA}; V_{CC} = 6.0 \text{ V}$	5.48	5.81	-	5.34	-	5.2	-	V
V_{OL}	LOW-level	$V_I = V_{IH}$ or V_{IL}								
	output voltage	$I_O = 20 \mu A; V_{CC} = 2.0 V$	-	0	0.1	-	0.1	-	0.1	V
		$I_O = 20 \mu A; V_{CC} = 4.5 V$	-	0	0.1	-	0.1	-	0.1	V
		$I_O = 20 \mu A; V_{CC} = 6.0 \text{ V}$	-	0	0.1	-	0.1	-	0.1	V
		$I_{O} = 4 \text{ mA}; V_{CC} = 4.5 \text{ V}$	-	0.15	0.26	-	0.33	-	0.4	V
		$I_{O} = 5.2 \text{ mA}; V_{CC} = 6.0 \text{ V}$	-	0.16	0.26	-	0.33	-	0.4	V
II	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 6.0 \text{ V}$	-	-	±0.1	-	±1.0	-	±1.0	μΑ
I _{CC}	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 6.0$ V	-	-	8.0	-	80	-	160	μΑ

 Table 6.
 Static characteristics ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

	<u> </u>	Table 1								1
Symbol	Parameter	Conditions		25 °C		–40 °C t	o +85 °C	–40 °C to	+125 °C	Unit
			Min	Тур	Max	Min	Max	Min	Max	
Cı	input capacitance		-	3.5	-	-	-	-	-	pF
74HCT12	23-Q100									
V_{IH}	HIGH-level input voltage	V_{CC} = 4.5 V to 5.5 V	2.0	1.6	-	2.0	-	2.0	-	V
V_{IL}	LOW-level input voltage	$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$	-	1.2	8.0	-	0.8	-	0.8	V
V _{OH}	HIGH-level	$V_I = V_{IH}$ or V_{IL} ; $V_{CC} = 4.5 \text{ V}$								
	output voltage	$I_{O} = -20 \mu A$	4.4	4.5	-	4.4	-	4.4	-	V
		$I_O = -4 \text{ mA}$	3.98	4.32	-	3.84	-	3.7	-	V
V_{OL}	LOW-level	$V_I = V_{IH}$ or V_{IL} ; $V_{CC} = 4.5 \text{ V}$								
	output voltage	I _O = 20 μA	-	0	0.1	-	0.1	-	0.1	V
		$I_{O} = 4.0 \text{ mA}$	-	0.15	0.26	-	0.33	-	0.4	V
l _l	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 5.5 \text{ V}$	-	-	±0.1	-	±1.0	-	±1.0	μΑ
I _{CC}	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 5.5 \text{ V}$	-	-	8.0	-	80	-	160	μΑ
Δl _{CC}	additional supply current	per input pin; $I_O = 0$ A; $V_I = V_{CC} - 2.1$ V; other inputs at V_{CC} or GND; $V_{CC} = 4.5$ V to 5.5 V								
		pins nĀ, nB	-	35	125	-	160	-	170	μΑ
		pin nRD	-	50	180	-	225	-	245	μΑ
C _I	input capacitance		-	3.5	-	-	-	-	-	pF

10. Dynamic characteristics

Table 7. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V); C_L = 50 pF unless otherwise specified; for test circuit see Figure 12.

Symbol	Parameter	Conditions			25 °C		-40 °C t	o +85 °C	-40 °C to	o +125 °C	Unit
				Min	Тур	Max	Min	Max	Min	Max	
74HC12	3-Q100					'	,			'	
t _{pd}	propagation delay	$\overline{\text{NRD}}$, $\overline{\text{NA}}$, $\overline{\text{NB}}$ to $\overline{\text{NQ}}$ or $\overline{\text{NQ}}$; $C_{\text{EXT}} = 0$ pF; $R_{\text{EXT}} = 5$ k Ω ; see Figure 9	[1]								
		V _{CC} = 2.0 V		-	83	255	-	320	-	385	ns
		$V_{CC} = 4.5 \text{ V}$		-	30	51	-	64	-	77	ns
		$V_{CC} = 5 \text{ V}; C_L = 15 \text{ pF}$		-	26	-	-	-	-	-	ns
		$V_{CC} = 6.0 \text{ V}$		-	24	43	-	54	-	65	ns
		$\overline{\text{NRD}}$ (reset) to nQ or $\overline{\text{NQ}}$; $C_{\text{EXT}} = 0 \text{ pF}$; $R_{\text{EXT}} = 5 \text{ k}\Omega$; see Figure 9									
		V _{CC} = 2.0 V		-	66	215	-	270	-	325	ns
		$V_{CC} = 4.5 \text{ V}$		-	24	43	-	54	-	65	ns
		$V_{CC} = 5 \text{ V}; C_L = 15 \text{ pF}$		-	20	-	-	-	-	-	ns
		$V_{CC} = 6.0 \text{ V}$		-	19	37	-	46	-	55	ns
t _t	transition	see Figure 9	[1]								
	time	$V_{CC} = 2.0 \text{ V}$		-	19	75	-	95	-	110	ns
		$V_{CC} = 4.5 \text{ V}$		-	7	15	-	19	-	22	ns
		$V_{CC} = 6.0 \text{ V}$		-	6	13	-	16	-	19	ns
t _W	pulse width	nA LOW; see Figure 10									
		V _{CC} = 2.0 V		100	8	-	125	-	150	-	ns
		V _{CC} = 4.5 V		20	3	-	25	-	30	-	ns
		$V_{CC} = 6.0 \text{ V}$		17	2	-	21	-	26	-	ns
		nB HIGH; see Figure 10									
		$V_{CC} = 2.0 \text{ V}$		100	17	-	125	-	150	-	ns
		$V_{CC} = 4.5 \text{ V}$		20	6	-	25	-	30	-	ns
		$V_{CC} = 6.0 \text{ V}$		17	5	-	21	-	26	-	ns
		nRD LOW; see Figure 11									
		$V_{CC} = 2.0 \text{ V}$		100	14	-	125	-	150	-	ns
		$V_{CC} = 4.5 \text{ V}$		20	5	-	25	-	30	-	ns
		$V_{CC} = 6.0 \text{ V}$		17	4	-	21	-	26	-	ns
		nQ HIGH and \overline{NQ} LOW; $V_{CC} = 5.0 \text{ V}$; see Figure 10 and Figure 11	[2]								
		C_{EXT} = 100 nF; R_{EXT} = 10 $k\Omega$		-	450	-	-	-	-	-	μS
		$C_{EXT} = 0 pF; R_{EXT} = 5 k\Omega$		-	75	-	-	-	-	-	ns

 Table 7.
 Dynamic characteristics ...continued

Voltages are referenced to GND (ground = 0 V); $C_L = 50$ pF unless otherwise specified; for test circuit see <u>Figure 12</u>.

Symbol	Parameter	Min Typ Max Min Max	+85 °C	-40 °C to	+125 °C	Unit					
				Min	Тур	Max	Min	Max	Min	Max	
t _{rtrig}	retrigger time	$n\overline{A}$, nB; $C_{EXT} = 0$ pF; $R_{EXT} = 5 \text{ k}\Omega$; $V_{CC} = 5.0 \text{ V}$; see Figure 10	[3][4]	-	110	-	-	-	-	-	ns
R _{EXT}	external	see Figure 7									
	resistance	$V_{CC} = 2.0 \text{ V}$		10	-	1000	-	-	-	-	kΩ
		$V_{CC} = 5.0 \text{ V}$		2	-	1000	-	-	-	-	kΩ
C _{EXT}	external capacitance	$V_{CC} = 5.0 \text{ V}$; see Figure 7	[4]	-	-	-	-	-	-	-	pF
C_{PD}	power dissipation capacitance	per monostable; $V_I = GND$ to V_{CC}	<u>[5]</u>	-	54	-	-	-	-	-	pF
74HCT1:	23-Q100										
t _{PHL}	HIGH to LOW propagation	$\overline{\text{NRD}}$, $\overline{\text{nA}}$, $\overline{\text{nB}}$ to $\overline{\text{nQ}}$ or $\overline{\text{nQ}}$; $C_{\text{EXT}} = 0$ pF; $R_{\text{EXT}} = 5$ k Ω ; see Figure 9									
	delay	$V_{CC} = 4.5 \text{ V}$		-	30	51	-	64	-	77	ns
		$V_{CC} = 5 \text{ V}; C_L = 15 \text{ pF}$		-	26	-	-	-	-	-	ns
		$\overline{\text{NRD}}$ (reset) to nQ or n $\overline{\text{Q}}$; $C_{\text{EXT}} = 0$ pF; $R_{\text{EXT}} = 5$ kΩ; see Figure 9									
		$V_{CC} = 4.5 \text{ V}$		-	27	46	-	58	-	69	ns
		$V_{CC} = 5 \text{ V}; C_L = 15 \text{ pF}$		-	23	-	-	-	-	-	ns
t _{PLH}	LOW to HIGH propagation	\overline{NRD} , \overline{NA} , \overline{NB} to \overline{NQ} or \overline{NQ} ; $\overline{C}_{EXT} = 0$ pF; $\overline{R}_{EXT} = 5$ k Ω ; see Figure 9									
	delay	$V_{CC} = 4.5 \text{ V}$		-	28	51	-	64	-	77	ns
		$V_{CC} = 5 \text{ V}; C_L = 15 \text{ pF}$		-	26	-	-	-	-	-	ns
		$\overline{\text{NRD}}$ (reset) to $\overline{\text{NQ}}$ or $\overline{\text{NQ}}$; $C_{\text{EXT}} = 0$ pF; $R_{\text{EXT}} = 5$ k Ω ; see Figure 9									
		$V_{CC} = 4.5 \text{ V}$		-	23	46	-	58	-	69	ns
		$V_{CC} = 5 \text{ V}; C_L = 15 \text{ pF}$		-	23	-	-	-	-	-	ns
t _t	transition time	V _{CC} = 4.5 V; see <u>Figure 9</u>	<u>[1]</u>	-	7	15	-	19	-	22	ns
t_W	pulse width	$V_{CC} = 4.5 \text{ V}$									
		nA LOW; see Figure 10		20	3	-	25	-	30	-	ns
		nB HIGH; see Figure 10		20	5	-	25	-	30	-	ns
		nRD LOW; see Figure 11		20	7	-	25	-	30	-	ns
		nQ HIGH and n \overline{Q} LOW; $V_{CC} = 5.0 \text{ V}$; see Figure 10 and Figure 11	[2]								
		C_{EXT} = 100 nF; R_{EXT} = 10 $k\Omega$		-	450	-	-	-	-	-	μS
		$C_{EXT} = 0 \text{ pF}; R_{EXT} = 5 \text{ k}\Omega$		-	75	-	-	-	-	-	ns
74HC_HCT123_	_Q100	All information prov	vided in this	document	is subject to	legal disclair	ners.		© NXP	B.V. 2012. All righ	nts reserve

Table 7. Dynamic characteristics ...continued

Voltages are referenced to GND (ground = 0 V); $C_L = 50 \text{ pF}$ unless otherwise specified; for test circuit see Figure 12.

Symbol	Parameter	Conditions			25 °C		-40 °C to	+85 °C	ks		Unit
			ı	Viin	Тур	Max	Min	Max	Min	Max	
t _{rtrig}	retrigger time	$n\overline{A}$, nB; $C_{EXT} = 0$ pF; $R_{EXT} = 5$ k Ω ; $V_{CC} = 5.0$ V; see Figure 10	<u>4]</u> ်	-	110	-	-	-	-	-	ns
R _{EXT}	external timing resistor	V _{CC} = 5.0 V; see <u>Figure 7</u>		2	-	1000	-	-	-	-	kΩ
C _{EXT}	external timing capacitor	$V_{CC} = 5.0 \text{ V}$; see Figure 7	4]	-	-	-	-	-	-	-	pF
C_{PD}	power dissipation capacitance	per monostable; $V_I = GND$ to V_{CC}	<u>5]</u>	-	56	-	-	-	-	-	pF

- [1] t_{pd} is the same as t_{PHL} and t_{PLH} ; t_t is the same as t_{THL} and t_{TLH}
- [2] For other R_{EXT} and C_{EXT} combinations, see Figure 7. If C_{EXT} > 10 nF, the following formula is valid.

 $t_W = K \times R_{EXT} \times C_{EXT}$, where:

t_W = typical output pulse width in ns;

 R_{EXT} = external resistor in $k\Omega$;

C_{EXT} = external capacitor in pF;

K = constant = 0.45 for $V_{CC} = 5.0$ V and 0.55 for $V_{CC} = 2.0$ V.

The inherent test jig and pin capacitance at pins 15 and 7 (nREXT/CEXT) is approximately 7 pF.

[3] The time to retrigger the monostable multivibrator depends on the values of R_{EXT} and C_{EXT} . The output pulse width is only extended when the time between the active-going edges of the trigger input pulses meets the minimum retrigger time. If $C_{\text{EXT}} > 10$ pF, the next formula (at $V_{\text{CC}} = 5.0$ V) for the setup time of a retrigger pulse is valid:

$$t_{rtrig}$$
 = 30 + 0.19 × R_{EXT} × $C_{EXT}^{0.9}$ + 13 × $R_{EXT}^{1.05}$, where:

 t_{rtrig} = retrigger time in ns;

 C_{EXT} = external capacitor in pF; R_{EXT} = external resistor in k Ω .

The inherent test jig and pin capacitance at pins 15 and 7 (nREXT/CEXT) is 7 pF.

- [4] When the device is powered-up, initiate the device via a reset pulse, when $C_{EXT} < 50$ pF.
- [5] C_{PD} is used to determine the dynamic power dissipation (P_D in μW).

$$P_D = C_{PD} \times V_{CC}{}^2 \times f_i + \sum (C_L \times V_{CC}{}^2 \times f_o) + 0.75 \times C_{EXT} \times V_{CC}{}^2 \times f_o + D \times 16 \times V_{CC} \text{ where:}$$

 f_i = input frequency in MHz;

f_o = output frequency in MHz;

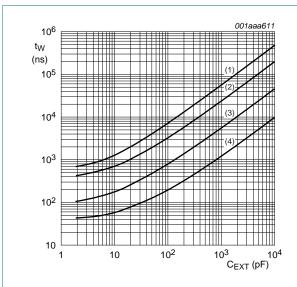
D = duty factor in %;

C_L = output load capacitance in pF;

V_{CC} = supply voltage in V;

C_{EXT} = timing capacitance in pF;

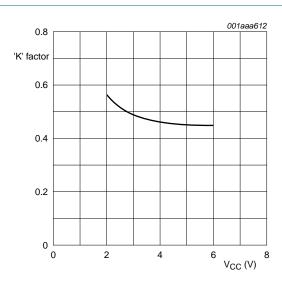
 $\sum (C_L \times V_{CC}{}^2 \times f_o)$ sum of outputs.



 V_{CC} = 5.0 V; T_{amb} = 25 °C.

- (1) $R_{EXT} = 100 \text{ k}\Omega$
- (2) $R_{EXT} = 50 \text{ k}\Omega$
- (3) $R_{EXT} = 10 \text{ k}\Omega$
- (4) $R_{EXT} = 2 k\Omega$

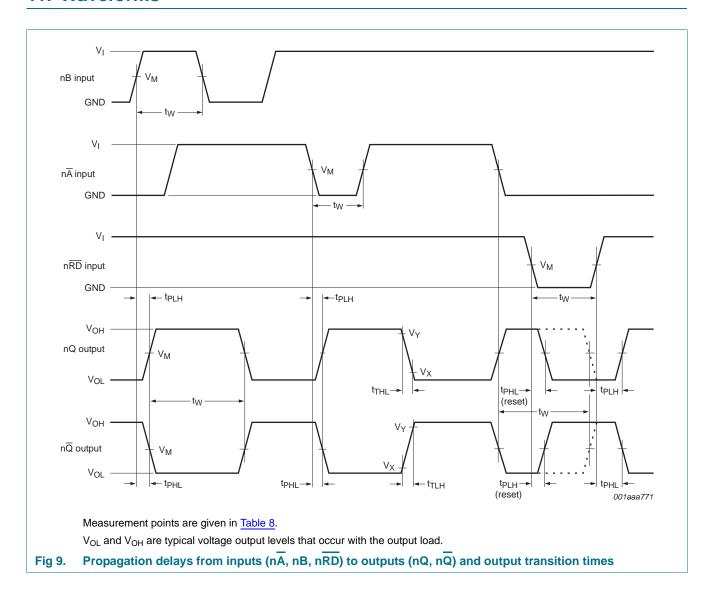
Fig 7. Typical output pulse width as a function of the external capacitor value

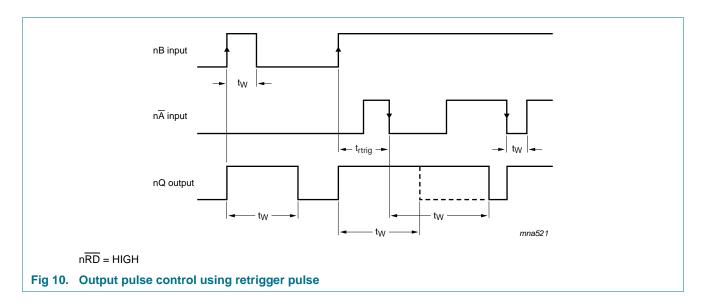


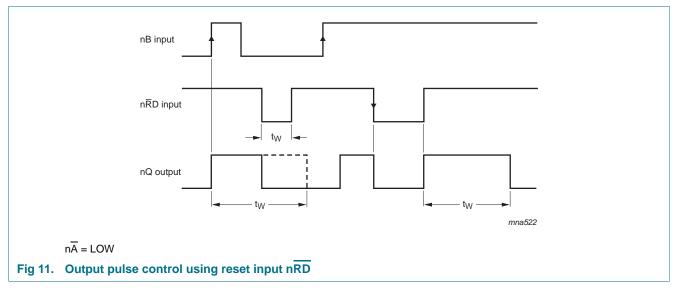
 C_{EXT} = 10 nF; R_{EXT} = 10 k Ω to 100 k Ω . T_{amb} = 25 °C.

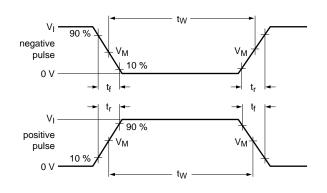
Fig 8. 74HC123-Q100 typical 'K' factor as function of V_{CC}

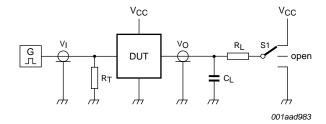
11. Waveforms











Test data is given in Table 8.

Definitions test circuit:

 R_T = Termination resistance should be equal to output impedance Z_0 of the pulse generator.

 C_L = Load capacitance including jig and probe capacitance.

 R_L = Load resistance.

S1 = Test selection switch.

Fig 12. Test circuit for measuring switching times

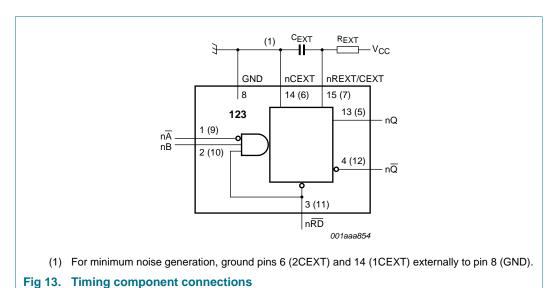
Table 8. Test data

Туре	Input		Load	Load			
	V _I	t _r , t _f	C _L	R _L	t _{PHL} , t _{PLH}		
74HC123-Q100	V _{CC}	6 ns	15 pF, 50 pF	1 kΩ	open		
74HCT123-Q100	3 V	6 ns	15 pF, 50 pF	1 kΩ	open		

12. Application information

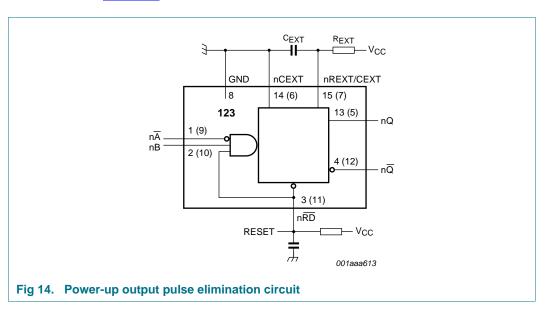
12.1 Timing component connections

The basic output pulse width is defined by the values of the external timing components R_{EXT} and C_{EXT} .



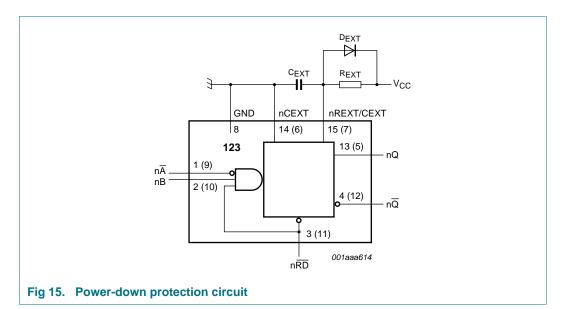
12.2 Power-up considerations

When the monostable is powered-up, it may produce an output pulse, with a pulse width defined by the values of R_{EXT} and C_{EXT} . This output pulse can be eliminated using the circuit shown in Figure 14.



12.3 Power-down considerations

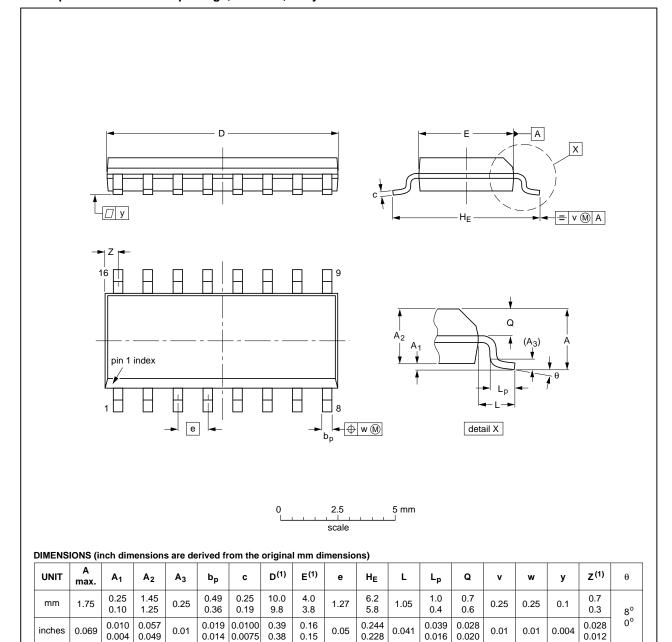
A large capacitor C_{EXT} may cause problems when powering-down the monostable due to the energy stored in this capacitor. When a system containing this device is powered-down or a rapid decrease of V_{CC} to zero occurs, the monostable may sustain damage. The damage is due to the capacitor discharging through the input protection diodes. To avoid this possibility, use a damping diode (D_{EXT}) and connect as shown in Figure 15. D_{EXT} is preferably a germanium or Schottky type diode able to withstand large current surges.



13. Package outline

SO16: plastic small outline package; 16 leads; body width 3.9 mm

SOT109-1



Note

1. Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.

OUTLINE		EUROPEAN	ISSUE DATE			
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
SOT109-1	076E07	MS-012				-99-12-27- 03-02-19

Fig 16. Package outline SOT109-1 (SO16)

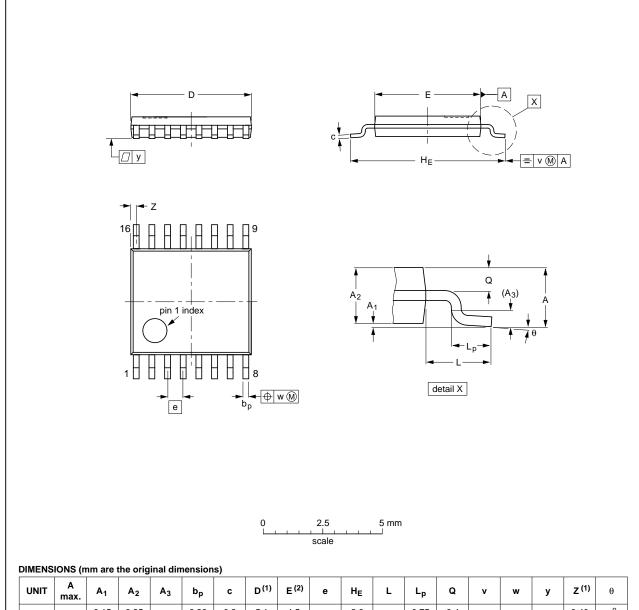
74HC_HCT123_Q100 All info

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TSSOP16: plastic thin shrink small outline package; 16 leads; body width 4.4 mm

SOT403-1



UNIT	A max.	A ₁	A ₂	A ₃	bp	С	D ⁽¹⁾	E (2)	е	HE	L	Lp	Q	v	w	у	Z ⁽¹⁾	θ
mm	1.1	0.15 0.05	0.95 0.80	0.25	0.30 0.19	0.2 0.1	5.1 4.9	4.5 4.3	0.65	6.6 6.2	1	0.75 0.50	0.4 0.3	0.2	0.13	0.1	0.40 0.06	8° 0°

- 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
- 2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

OUTLINE		REFER	EUROPEAN	ISSUE DATE			
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE	
SOT403-1		MO-153				99-12-27 03-02-18	

Fig 17. Package outline SOT403-1 (TSSOP16)

74HC_HCT123_Q100

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DHVQFN16: plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 16 terminals; body 2.5 x 3.5 x 0.85 mm SOT763-1

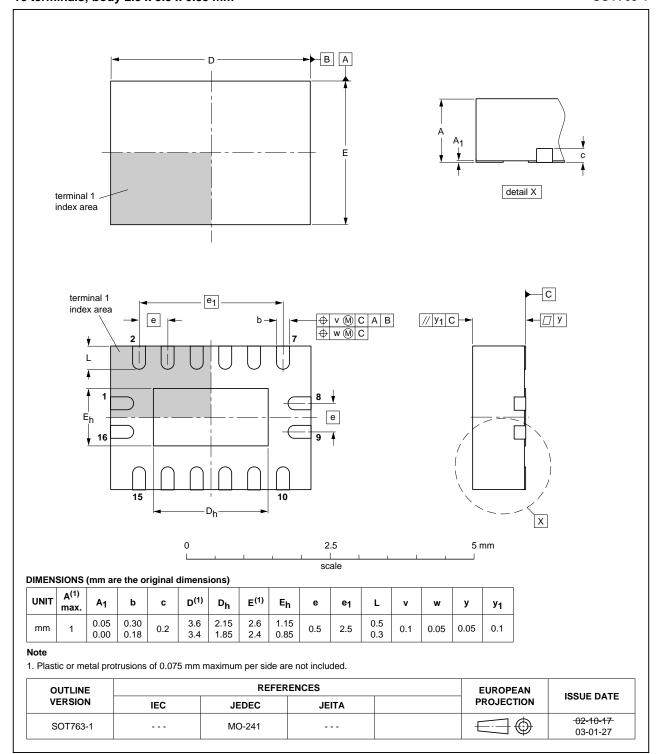


Fig 18. Package outline SOT763-1 (DHVQFN16)

74HC_HCT123_Q100

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14. Abbreviations

Table 9. Abbreviations

Acronym	Abbreviation					
CMOS	Complementary Metal Oxide Semiconductor					
DUT	Device Under Test					
ESD	ElectroStatic Discharge					
HBM	Human Body Model					
LSTTL	Low-power Schottky Transistor-Transistor Logic					
MM	Machine Model					
MIL	Military					

15. Revision history

Table 10. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
74HC_HCT123_Q100 v.1	20120801	Product data sheet	-	-

16. Legal information

16.1 Data sheet status

Document status[1][2]	Product status[3]	Definition				
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.				
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.				
Product [short] data sheet	Production	This document contains the product specification.				

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

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74HC123-Q100; 74HCT123-Q100

Dual retriggerable monostable multivibrator with reset

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Dual retriggerable monostable multivibrator with reset

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